

P-CHANNEL ENHANCEMENT MODE MOSFET WITH INTEGRATED SBR[®] SUPER BARRIER RECTIFIER

Features

- Low On-Resistance
 - 95mΩ @V_{GS} = -4.5V
 - 120mΩ @V_{GS} = -2.5V
 - 86mΩ (typ) @V_{GS} = -1.8V
 - Low Gate Threshold Voltage, -1.3V Max
- Fast Switching Speed
- Low Input/Output Leakage
- Incorporates Low V_F Super Barrier Rectifier (SBR)
- Low Profile, 0.5mm Max Height
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

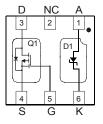
Mechanical Data

- Case: U-DFN2020-6 Type B
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Weight: 0.0065 grams (approximate)

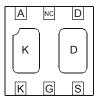
U-DFN2020-6

Type B

Bottom View



Top View Internal Schematic



Bottom View Pin Configuration

Ordering Information (Note 4)

Case	Packaging
U-DFN2020-6 Type B	3000/Tape & Reel
_	LI-DEN2020-6 Type B

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and

<1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com.

Marking Information

Data Orda Ka

Notes:



ME = Marking Code YM = Date Code Marking Y = Year (ex: V = 2008) M = Month (ex: 9 = September) Dot denotes Pin 1

Date Code Key			-									
Year	2008	2009	20	10	2011	2012	2013	2014	20)15	2016	2017
Code	V	W)	Κ	Y	Z	А	В		С	D	E
Month	Jan	Feb	Mar	Apr	Mav	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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Maximum Ratings – TOTAL DEVICE (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	1.4	W
Thermal Resistance, Junction to Ambient	R _{0JA}	89	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	C°

Maximum Ratings – P-CHANNEL MOSFET – Q1 (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Drain-Source Voltage	V _{DSS}	-20	V
Gate-Source Voltage	V _{GSS}	±12	V
Drain Current (Note 5)	ID	-3.5	А
Pulsed Drain Current (Note 6)	I _{DM}	-12	А

Maximum Ratings – SBR – D1 (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	20	V
RMS Reverse Voltage	V _{R(RMS)}	14	V
Average Rectified Output Current	lo	1	А
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load	I _{FSM}	3	A

Electrical Characteristics – P-CHANNEL MOSFET – Q1 (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	2					
Drain-Source Breakdown Voltage	BV _{DSS}	-20	_	—	V	V _{GS} = 0V, I _D = -250µA
Zero Gate Voltage Drain Current	IDSS	_	_	-1	μA	$V_{DS} = -20V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}	_	—	±100 ±800	nA	$V_{GS} = \pm 8V, V_{DS} = 0V$ $V_{GS} = \pm 12V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)		-	-		-	
Gate Threshold Voltage	V _{GS(th)}	-0.45	_	-1.3	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$
		_	60	95		V _{GS} = -4.5V, I _D = -2.8A
Static Drain-Source On-Resistance	R _{DS(ON)}	—	74	120	mΩ	V _{GS} = -2.5V, I _D = -2.0A
		_	86	-		V _{GS} = -1.8V, I _D = -1.0A
Forward Transfer Admittance	Y _{fs}		8	—	S	V _{DS} = -5V, I _D = -2.8A
Diode Forward Voltage (Note 7)	V _{SD}	—	0.7	-1.2	V	V _{GS} = 0V, I _S = -1.6A
DYNAMIC CHARACTERISTICS						
Input Capacitance	Ciss	_	632	—	pF	101/11/01/
Output Capacitance	C _{oss}	_	65	—	pF	V _{DS} = -10V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	54	—	pF	

Electrical Characteristics – SBR – D1 (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 7)	V _{(BR)R}	20	—		V	I _R = 1mA
Forward Voltage	V _F		-	0.45 0.52	V	I _F = 0.5A I _F = 1.0A
Reverse Current (Note 7)	I _R	_	_	100	μA	V _R = 20V

Notes: 5. Device mounted on FR-4 PCB, on minimum recommended, 2oz Copper pad layout.

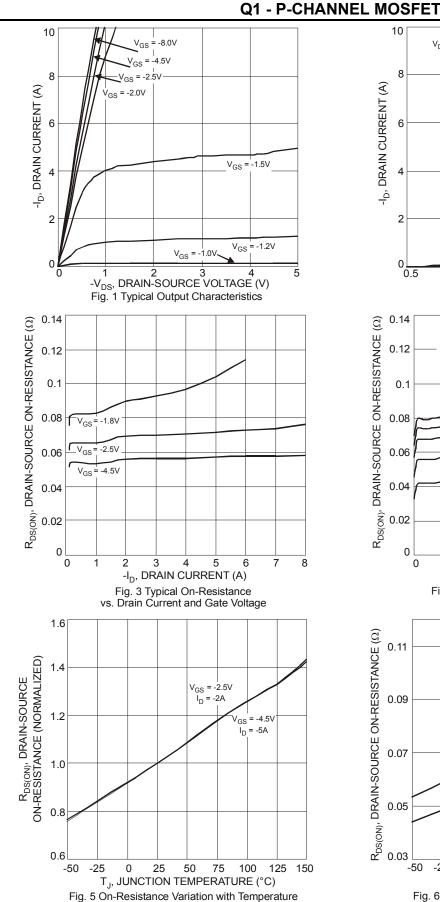
6. Repetitive rating, pulse width limited by junction temperature.

7. Short duration pulse test used to minimize self-heating effect.

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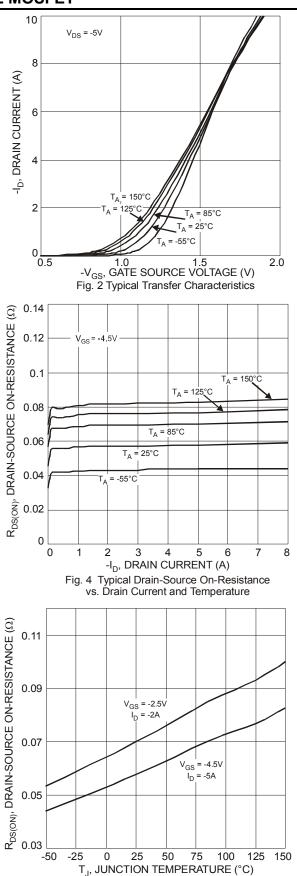
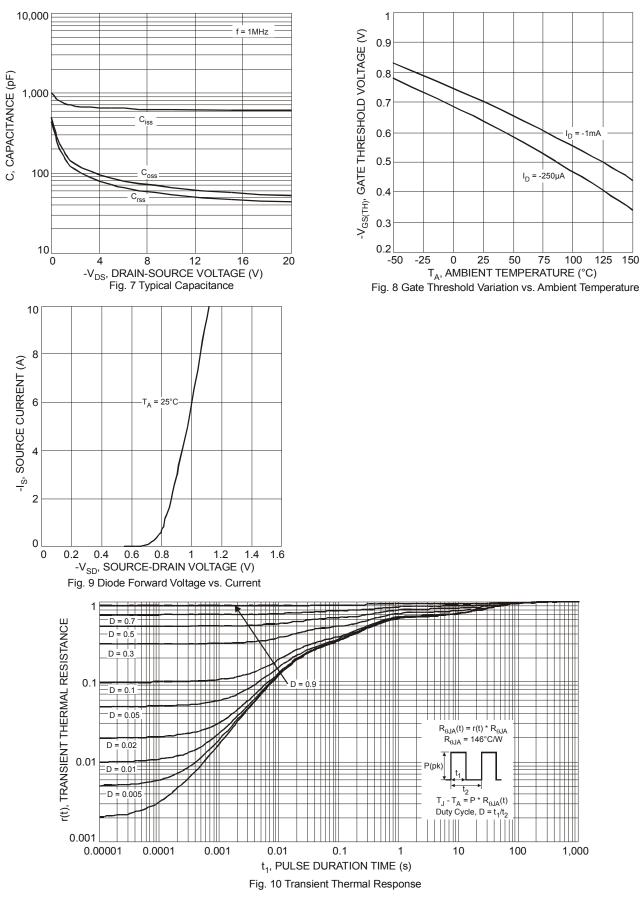


Fig. 6 On-Resistance Variation with Temperature

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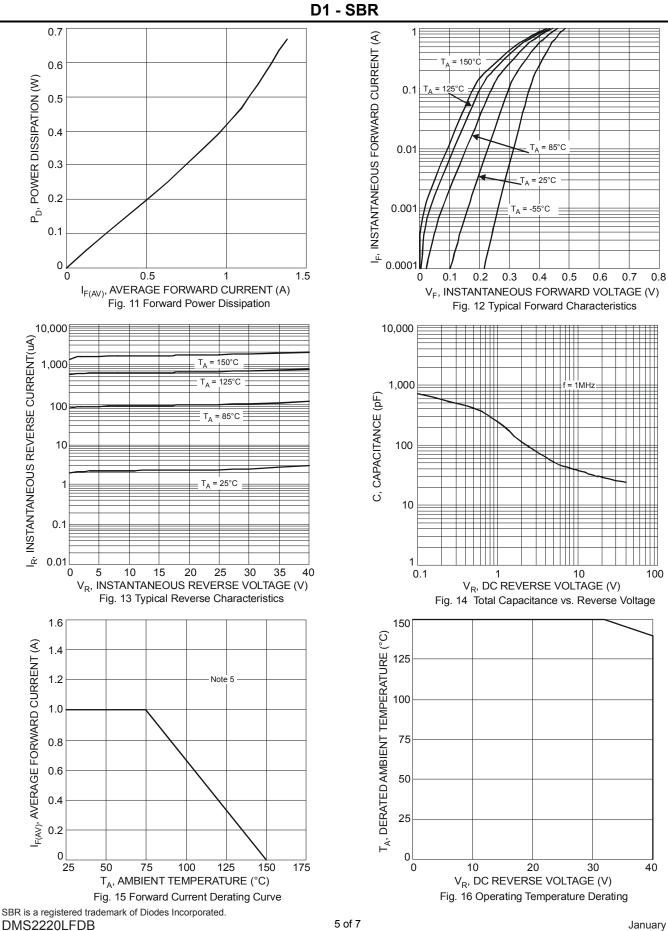




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DMS2220LFDB





Тур

0.575

0.02

0.13

0.25

2.00

0.45

0.60

0.65

2.00

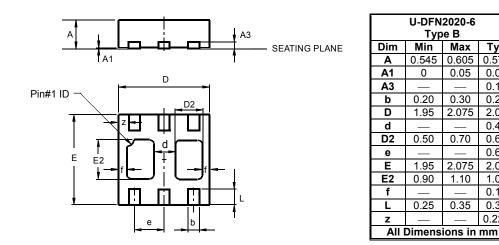
1.00

0.15

0.30 0.225

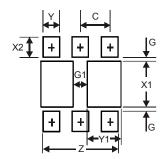
Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	1.67
G	0.20
G1	0.40
X1	1.0
X2	0.45
Y	0.37
Y1	0.70
С	0.65



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